

JAN2N6766 Information


For Reference Only

Part Number [JAN2N6766](#)
Manufacturer Microsemi Corporation
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description MOSFET N-CH TO-204AE TO-3
Package TO-204AE
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


JAN2N6766 Specifications

Manufacturer Part Number	JAN2N6766
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	TO-204AE
Series	Military, MIL-PRF-19500/543
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	200V
Current - Continuous Drain (Id) @ 25°C	30A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	115nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	-
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	4W (Ta), 150W (Tc)
Rds On (Max) @ Id, Vgs	90 mOhm @ 30A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-3
Package / Case	TO-204AE

[Report errors?](#)

JAN2N6766 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

JAN2N6766 Payment Methods



JAN2N6766 Shipping Methods



If you have any question about JAN2N6766, please do not hesitate to contact us!

Website: <https://www.heisener.com>

E-mail: salesdept@heisener.com